

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Diodes Incorporated</u> 74LVC2G07FZ4-7

For any questions, you can email us directly: sales@integrated-circuit.com



Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





74LVC2G07

DUAL BUFFERS WITH OPEN DRAIN OUTPUTS

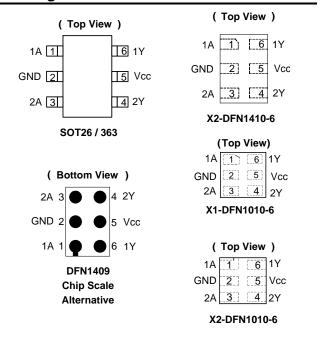
Description

The 74LVC2G07 is a dual buffer gate with open drain outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The input is tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down. The open-drain output can be connected to other open drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32mA.

Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- -24mA Output Drive at 3.0V
- **CMOS Low Power Consumption**
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- DFN1409 Package Designed as a Direct Replacement for Chip Scale Packaging
- Range of Package Options SOT26, SOT363, X1-DFN1010-6, X2-DFN1010-6, X2-DFN1409-6, and X2-DFN1410-6
- Leadless Packages Named per JESD30E
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
 - Wide Array of Products Such as:
 - PCs, Networking, Notebooks, Netbooks, Tablets
 - Computer Peripherals, Hard Drives, SSD, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box
 - Cell Phones, Personal Navigation / GPS
 - MP3 Players, Cameras, Video Recorders

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

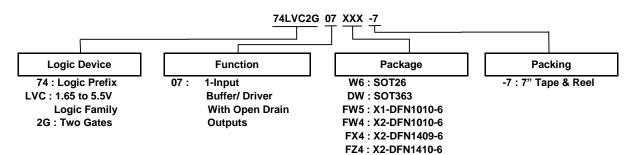
Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



74LVC2G07

Ordering Information



Part Number	Package	Package	Package	7" Tape and R	eel (Note 5)
Part Number	Code	(Note 4)	Size	Quantity	Part Number Suffix
74LVC2G07W6-7	W6	SOT26	2.8mm X 2.2mm X 1.1mm 0.95mm lead pitch	3000/Tape & Reel	-7
74LVC2G07DW-7	DW	SOT363	2.0mm X 2.0mm X 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7
74LVC2G07FW5-7	FW5	X1-DFN1010-6	1.0mm X 1.0mm X 0.5mm 0.35mm pad pitch	5000/Tape & Reel	-7
74LVC2G07FW4-7	FW4	X2-DFN1010-6	1.0mm X 1.0mm X 0.4mm 0.35mm pad pitch	5000/Tape & Reel	-7
74LVC2G07FX4-7	FX4	X2-DFN1409-6 Chip Scale Alternative	1.4mm X 0.9mm X 0.4mm 0.5mm pad pitch	5000/Tape & Reel	-7
74LVC2G07FZ4-7	FZ4	X2-DFN1410-6	1.4mm X 1.0mm X 0.4mm 0.5mm pad pitch	5000/Tape & Reel	-7

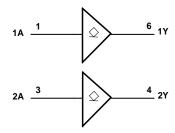
Notes:

- 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 5. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	GND	Ground
3	2A	Data Input
4	2Y	Data Output Open Drain
5	Vcc	Supply Voltage
6	1Y	Data Output Open Drain

Logic Diagram



Function Table

Inputs	Output
Α	Υ
Н	Z
L	L

Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



74LVC2G07

Absolute Maximum Ratings (Notes 6, 7) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +6.5	V
VI	Input Voltage Range	-0.5 to +6.5	V
Vo	Voltage Applied to Output in High Impedance or I _{OFF} State	-0.5 to +6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V ₁ < 0	-50	mA
I _{OK}	Output Clamp Current V _O < 0	-50	mA
Io	Continuous Output Current	-50	mA
_	Continuous Current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

- 6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could Cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8) (@T_A = +25°C, unless otherwise specified.)

Symbol		Parameter	Min	Max	Unit
V	Operating Voltage	Operating	1.65	5.5	V
V _{CC}	Operating Voltage	Data Retention Only	1.5	_	V
		V _{CC} = 1.65V to 1.95V	0.65 X V _{CC}	_	
.,	Lligh Lovel Innut Voltage	$V_{CC} = 2.3V \text{ to } 2.7V$	1.7	_	V
V _{IH}	High-Level Input Voltage	V _{CC} = 3V to 3.6V	2	-	V
		V _{CC} = 4.5V to 5.5V	0.7 X V _{CC}	-	
		V _{CC} = 1.65V to 1.95V	_	0.35 X V _{CC}	
.,,	Lauri anal lagrit Maltaga	V _{CC} = 2.3V to 2.7V	_	0.7	.,
V _{IL}	Low-Level Input Voltage	V _{CC} = 3V to 3.6V	_	0.8	V
		V _{CC} = 4.5V to 5.5V	_	0.3 X V _{CC}	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 1.65V	_	4	
		$V_{CC} = 2.3V$	_	8	
I _{OL}	Low-Level Output Current	V 2V	_	16	mA
		V _{CC} = 3V	_	24	
		$V_{CC} = 4.5V$	_	32	
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$	_	20	
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 3.3V \pm 0.3V$	-	10	ns/V
	1100	$V_{CC} = 5V \pm 0.5V$	-	10	
T _A	Operating Free-air Temperature	-	-40	+125	°C

Note: 8. Unused inputs should be held at V_{CC} or Ground.

Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



74LVC2G07

Electrical Characteristics

Cumbal	Parameter	Test Conditions	Vcc	-40°C to	o +85°C	-40°C to	+125°C	Unit
Symbol	Parameter	Parameter Test Conditions		Min	Max	Min	Max	Unit
		I _{OL} = 100μA	1.65V to 5.5V	_	0.1	_	0.1	
		$I_{OL} = 4mA$	1.65V	-	0.45	-	0.70	
.,	Love Lovel Output Valtage	I _{OL} = 8mA	2.3V	-	0.3	-	0.45	v
V_{OL}	Low Level Output Voltage	I _{OL} = 16mA	3V	_	0.4	_	0.60	V
		$I_{OL} = 24mA$	3 V	_	0.55	_	0.80	
		$I_{OL} = 32mA$	4.5V	_	0.55	_	0.80	
II	Input Current	$V_I = 5.5V$ or GND	0 to 5.5V	-	±5	-	±20	μA
loz	Z State Leakage Current	$V_0 = 0 \text{ to } 5.5V$	3.6V	-	±10	-	±10	μA
loff	Power Down Leakage Current	V_I or $V_O = 5.5V$	0V	-	±10	-	±20	μA
Icc	Supply Current	$V_{I} = 5.5V$ or GND, $I_{O} = 0$	1.65V to 5.5V	-	10	_	40	μA
Δlcc	Additional Supply Current	Input at V _{CC} –0.6V	3V to 5.5V	_	500	_	5000	μA

Package Characteristics (@T_A = +25°C, V_{CC} = 3.3V, unless otherwise specified.)

Symbol	Parameter	Package	Conditions	Min	Тур	Max	Unit	
Cı	Input Capacitance	Typical of All Packages	Vcc = 3.3V $V_1 = V_{CC}$ or GND	_	3.5	-	pF	
		SOT26		_	204	_		
		SOT363		_	371	_		
0	Thermal Resistance Junction-to-	X2-DFN1410-6	(Note O)	_	430	_	°C/W	
θ_{JA}	Ambient	X2-DFN1409-6	(Note 9)	_	450	_	*C/VV	
		X1-DFN1010-6		_	495	_		
		X2-DFN1010-6		_	510	_		
		SOT26		_	52	_		
		SOT363		_	143	_		
0	Thermal Resistance Junction-to-	X2-DFN1410-6	(Note O)	_	190	_	°C/W	
θ_{JC}	Case	X2-DFN1409-6	(Note 9)	(Note 9)	_	225	_	*C/VV
		X1-DFN1010-6		_	245	_	1	
		X2-DFN1010-6		-	250	_		

Note: 9. Test condition for all packages: Device mounted on FR-4 substrate PC board, 2oz copper with minimum recommended pad layout.

Switching Characteristics

 $T_A = -40$ °C to +85°C, $C_L = 30$ or 50pF (see Figure 1)

Parameter	From (Input)	To (Output)		: 1.8V 15V		: 2.5V .2V	V _{CC} = ±0	: 3.3V .3V	V _{CC} :		Unit
	(iliput)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PD}	А	Y	0.5	6.7	0.5	4.3	0.5	3.7	0.5	2.9	ns

 $T_A = -40$ °C to +125°C, $C_L = 30$ or 50pF (see Figure 1)

Parameter	From (Input)	To (Output)		= 1.8V 15V		: 2.5V .2V		: 3.3V .3V	V _{CC} :		Unit
	(input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PD}	A	Y	0.5	8.4	0.5	5.5	0.5	4.7	0.5	3.7	ns

Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



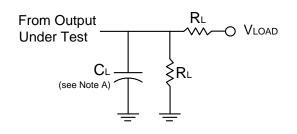
74LVC2G07

Operating Characteristics

\mathbf{T}_{i}	٠.	= 4	-2	5	'n

	Parameter	Test	V _{CC} = 1.8V	V _{CC} = 2.5V	V _{CC} = 3.3V	V _{CC} = 5V	Unit
	i didilictei	Conditions	Тур	Тур	Тур	Тур	Onic
C _{PD}	Power Dissipation Capacitance	f = 10MHz	3	3	4	6	pF

Parameter Measurement Information



TEST	Condition
t _{PLZ} (see Notes D and E)	V_{LOAD}
t _{PZL} (see Notes D and F)	V_{LOAD}

V	Inputs		V	V	•	В	
V _{CC}	VI	t _r /t _f	V _M	V_{LOAD}	CL	R_L	V Δ
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	1kΩ	0.15V
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	2 X V _{CC}	50pF	500Ω	0.3V

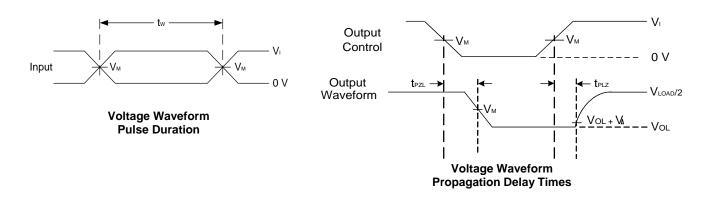


Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD} .
- E. t_{PZL} is measured at V_{M} .
- F. t_{PLZ} is measured at V_{OL} + V_{Δ} .

Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

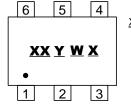
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



74LVC2G07

Marking Information

(1) SOT26, SOT363



 $\frac{XX}{Y}: Identification Code \\ \underline{Y}: Year 0~9$

 $\overline{\underline{W}}$: Week : A~Z : 1~26 Week;

a~z: 27~52 Week; z Represents

52 and 53 Week \underline{X} : A~Z: Internal Code

Part Number	Package	Identification Code
74LVC2G07W6-7	SOT26	Z4
74LVC2G07DW-7	SOT363	Z 4

(2) X1-DFN1010-6, X2-DFN1010-6, X2-DFN1409-6, X2-DFN1410-6

(Top View)

XX $\frac{XX}{Y}: Identification Code \\ \underline{Y}: Year 0~9$

 $\overline{\underline{W}}$: Week: A~Z: 1~26 Week; a~z: 27~52 Week; z Represents

52 and 53 Week

X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC2G07FW4-7	X2-DFN1010-6	Z4
74LVC2G07FW5-7	X1-DFN1010-6	W4
74LVC2G07FX4-7	X2-DFN1409-6	X4
74LVC2G07FZ4-7	X2-DFN1410-6	Z4

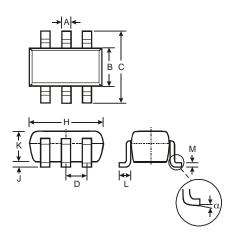
Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

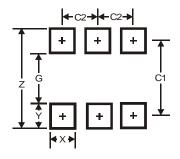


74LVC2G07

SOT26 Package Outline Dimensions and Suggested Pad Layout



	SOT26				
Dim	n Min Max Typ				
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D			0.95		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
K	1.00	1.30	1.10		
L	0.35	0.55	0.40		
М	0.10	0.20	0.15		
α	0°	8°			
All Dimensions in mm					



Dimensions	Value (in mm)	
Z	3.20	
G	1.60	
Х	0.55	
Υ	0.80	
C1	2.40	
C2	0.95	

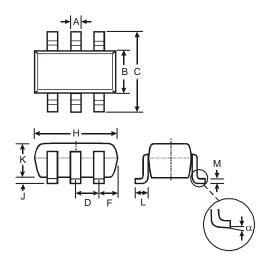
Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

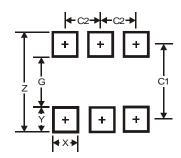


74LVC2G07

SOT363 Package Outline Dimensions and Suggested Pad Layout



	SOT363			
Dim	Min	Max	Тур	
Α	0.10	0.30	0.25	
В	1.15	1.35	1.30	
С	2.00	2.20	2.10	
D	0.65 Typ			
F	0.40	0.45	0.425	
Н	1.80	2.20	2.15	
J	0	0.10	0.05	
K	0.90	1.00	1.00	
L	0.25	0.40	0.30	
М	0.10	0.22	0.11	
α	0°	8°	-	
All Dimensions in mm				



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65

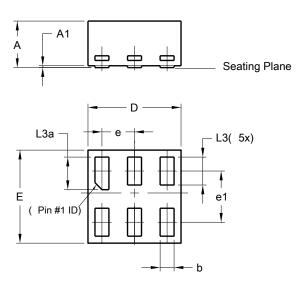
Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

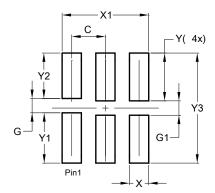


74LVC2G07

X1-DFN1010-6 (Type B) Package Outline Dimensions and Suggested Pad Layout



X1-DFN1010-6 (Type B)					
Dim	Min				
Α	-	0.50	0.39		
A1		- 0.04 -			
b	0.12 0.20 0.15				
D	0.95	0.95 1.050 1.00			
Е	0.95	1.050	1.00		
е		0.35 B	SC		
e1		0.55 BSC			
L3	0.27	0.30	0.30		
L3a	0.32	0.40	0.35		
All Dimensions in mm					



Dimensions	Value	
פווטופוופווט	(in mm)	
С	0.350	
G	0.150	
G1	0.150	
X	0.200	
X1	0.900	
Υ	0.500	
Y1	0.525	
Y2	0.475	
Y3	1.150	

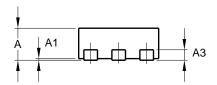
Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

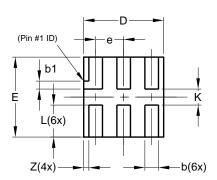
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



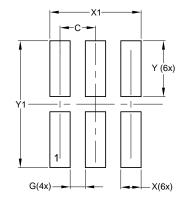
74LVC2G07

X2-DFN1010-6 Package Outline Dimensions and Suggested Pad Layout





X2-DFN1010-6			
Dim	Min	Max	Тур
Α		0.40	0.39
A1	0.00	0.05	0.02
A3			0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
Е	0.95	1.05	1.00
e			0.35
١	0.35	0.45	0.40
K	0.15	_	
Z	_	_	0.065
All Dimensions in mm			

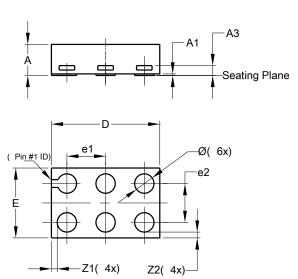


Dimensions	Value (in mm)	
С	0.350	
G	0.150	
Х	0.200	
X1	0.900	
Υ	0.550	
Y1	1.250	

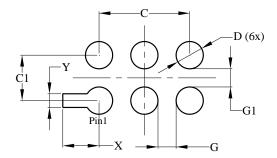


74LVC2G07

X2-DFN1409-6 Package Outline Dimensions and Suggested Pad Layout



X2-DFN1409-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0	0.05	0.02
A3		1	0.13
Ø	0.20	0.30	0.25
D	1.35	1.45	1.40
Е	0.85	0.95	0.90
e1		1	0.50
e2		l	0.50
Z1			0.075
Z2		_	0.075
All Dimensions in mm			



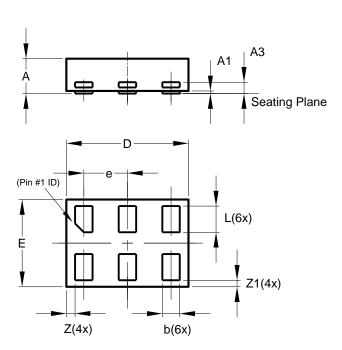
Dimensions	Value (in mm)	
С	1.000	
C1	0.500	
D	0.300	
G	0.200	
G1	0.200	
Х	0.400	
Υ	0.150	



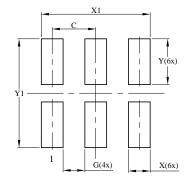


74LVC2G07

X2-DFN1410-6 **Package Outline Dimensions and Suggested Pad Layout**



X2-DFN1410-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0.00	0.05	0.02
A3			0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
Е	0.95	1.05	1.00
е			0.50
L	0.25	0.35	0.30
Z			0.10
Z1	0.045	0.105	0.075
All Dimensions in mm			



Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.250
X1	1.250
Υ	0.525
Y1	1.250



Datasheet of 74LVC2G07FZ4-7 - IC BUFF/DVR O/D DFN1410-6

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



74LVC2G07

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

74LVC2G07 13 of 13 March 2015

Document number: DS35162 Rev. 6 - 2 www.diodes.com © Diodes Incorporated